

## High Speed, Four Channel MOSFET Driver with Non-Inverting Outputs

### Features

- ▶ Non-inverting, four channel MOSFET driver
- ▶ 6.0ns rise and fall time
- ▶ 2.0A peak output source/sink current
- ▶ 1.8 to 5.0V input CMOS compatible
- ▶ 5.0 to 10V total supply voltage
- ▶ Smart logic threshold
- ▶ Low jitter design
- ▶ Four matched channels
- ▶ Drives two P- and two N-channel MOSFETs
- ▶ Outputs can swing below ground
- ▶ Low inductance quad flat no-lead package
- ▶ High performance, thermally-enhanced package

### Applications

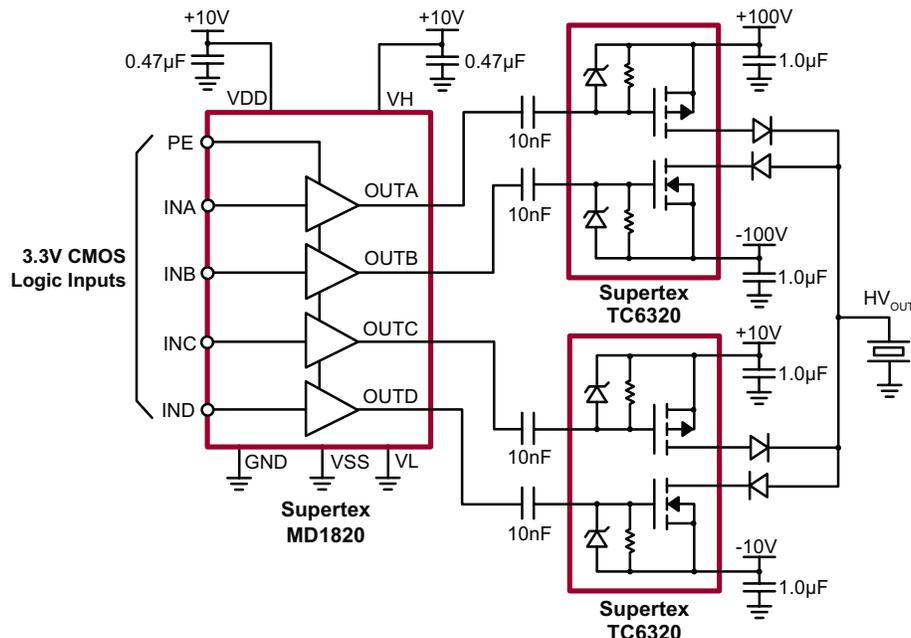
- ▶ Medical ultrasound imaging
- ▶ Piezoelectric transducer drivers
- ▶ Non-Destructive Testing (NDT)
- ▶ PIN diode driver
- ▶ CCD Clock driver/buffer
- ▶ High speed level translator

### General Description

The Supertex MD1820 is a high speed, four channel MOSFET driver designed to drive high voltage P- and N-channel MOSFETs for medical ultrasound applications and other applications requiring a high output current for a capacitive load. The high-speed input stage of the MD1820 can operate from a 1.8 to 5.0V logic interface with an optimum operating input signal range of 1.8 to 3.3V. An adaptive threshold circuit is used to set the level translator switch threshold to the average of the input logic 0 and logic 1 levels. The input logic levels may be ground-referenced, even though the driver is putting out bipolar signals. The level translator uses a proprietary circuit, which provides DC coupling together with high-speed operation.

The output stage of the MD1820 has separate power connections enabling the output signal L and H levels to be chosen independently from the supply voltages used for the majority of the circuit. As an example, the input logic levels may be 0 and 1.8V, the control logic may be powered by +5.0 and -5.0V, and the output L and H levels may be varied anywhere over the range of -5.0 to +5.0V. The output stage is capable of peak currents of up to  $\pm 2.0A$ , depending on the supply voltages used and load capacitance present. The PE pin serves a dual purpose. First, its logic H level is used to compute the threshold voltage level for the channel input level translators. Second, when PE is low, the outputs are HiZ. This assists in properly precharging the AC coupling capacitors that may be used in series in the gate drive circuit of an external PMOS and NMOS transistor pair.

### Typical Application Circuit



## Ordering Information

Device	16-Lead QFN 3.00x3.00mm body 1.00mm height (max) 0.50mm pitch
MD1820	MD1820K6-G

-G indicates package is RoHS compliant ("Green")



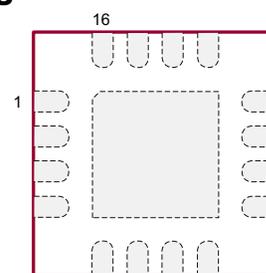
## Absolute Maximum Ratings

Parameter	Value
$V_{DD}-V_{SS}$ , Logic supply voltage	-0.5V to +12.5V
$V_H$ , Output high supply voltage	$V_L - 0.5V$ to $V_{DD} + 0.5V$
$V_L$ , Output low supply voltage	$V_{SS} - 0.5V$ to $V_H + 0.5V$
$V_{SS}$ , Low side supply voltage	-6.0V to +0.5V
Logic input levels	$V_{SS} - 0.5V$ to GND +5.5V
Maximum junction temperature	+125°C
Storage temperature	-65°C to 150°C
Operating temperature	-20°C to +85°C
Package power dissipation	2.2W
Thermal resistance ( $\theta_{JA}$ )*	55°C/W

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

\* 1.0oz 4-layer 3x4" PCB

## Pin Configuration



16-Lead QFN (K6)  
(top view)

## Product Marking



Y = Last Digit of Year Sealed  
W = Code for Week Sealed  
L = Lot Number  
— = "Green" Packaging

Package may or may not include the following marks: Si or

16-Lead QFN (K6)

DC Electrical Characteristics ( $V_H = V_{DD} = 10V$ ,  $V_L = V_{SS} = GND = 0V$ ,  $V_{PE} = 3.3V$ ,  $T_A = 25^\circ C$ )

Sym	Parameter	Min	Typ	Max	Units	Conditions
$V_{DD} - V_{SS}$	Logic supply voltage	4.75	-	11.5	V	$4.0V \leq V_{DD} \leq 11.5V$
$V_{SS}$	Low side supply voltage	-5.5	-	0	V	---
$V_H$	Output high supply voltage	$V_{SS} + 2.0$	-	$V_{DD}$	V	---
$V_L$	Output low supply voltage	$V_{SS}$	-	$V_{DD} - 4.0$	V	---
$I_{DDQ}$	$V_{DD}$ quiescent current	-	60	-	$\mu A$	No input transitions, PE = 0
$I_{HQ}$	$V_H$ quiescent current	-	2.0	-	$\mu A$	
$I_{DDQ}$	$V_{DD}$ quiescent current	-	0.8	-	mA	No input transitions, PE = 1
$I_{HQ}$	$V_H$ quiescent current	-	2.0	-	$\mu A$	
$I_{DD}$	$V_{DD}$ average current	-	3.5	-	mA	One channel on at 5.0Mhz, No load
$I_H$	$V_H$ average current	-	10	-	mA	
$V_{IH}$	Input logic voltage high	$V_{PE} - 0.3$	-	$V_{PE}$	V	For logic inputs INA, INB, INC, and IND
$V_{IL}$	Input logic voltage low	0	-	0.3	V	
$I_{IH}$	Input logic current high	-	-	1.0	$\mu A$	
$I_{IL}$	Input logic current low	-	-	1.0	$\mu A$	
$V_{IH}$	PE input logic voltage high	1.70	3.30	5.25	V	For logic input PE
$V_{IL}$	PE input logic voltage low	0	-	0.3	V	
$R_{IN PE}$	PE input impedance to GND	100	-	-	K $\Omega$	

**DC Electrical Characteristics (cont.)** ( $V_H = V_{DD} = 10V$ ,  $V_L = V_{SS} = GND = 0V$ ,  $V_{PE} = 3.3V$ ,  $T_A = 25^\circ C$ )

Sym	Parameter	Min	Typ	Max	Units	Conditions
$C_{IN}$	Logic input capacitance	-	5.0	10	pF	---
$R_{SINK}$	Output sink resistance	-	1.5	-	$\Omega$	$I_{SINK} = 50mA$
$R_{SOURCE}$	Output source resistance	-	2.0	-	$\Omega$	$I_{SOURCE} = 50mA$
$I_{SINK}$	Peak output sink current	-	2.0	-	A	---
$I_{SOURCE}$	Peak output source current	-	2.0	-	A	---

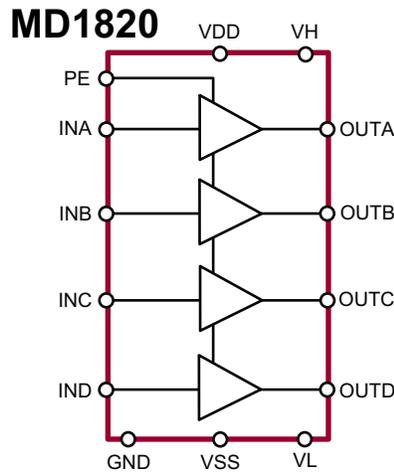
**AC Electrical Characteristics** ( $V_H = V_{DD} = 10V$ ,  $V_L = V_{SS} = GND = 0V$ ,  $V_{PE} = 3.3V$ ,  $T_A = 25^\circ C$ )

Sym	Parameter	Min	Typ	Max	Units	Conditions
$t_{irf}$	Input or PE rise & fall time	-	-	10	ns	Logic input edge speed requirement
$t_{PLH}$	Propagation delay when output is from low to high	-	6.5	-	ns	$C_{LOAD} = 1000pF$ , see timing diagram
$t_{PHL}$	Propagation delay when output is from high to low	-	6.5	-	ns	
$t_r$	Output rise time	-	7.0	-	ns	Input signal rise/fall time 2.0ns
$t_f$	Output fall time	-	7.0	-	ns	
$ t_r - t_f $	Rise and fall time matching	-	1.0	-	ns	For each channel
$ t_{PLH} - t_{PHL} $	Propagation low to high and high to low matching	-	1.0	-	ns	
$\Delta t_{dm}$	Propagation delay matching	-	$\pm 2.0$	-	ns	Device to device delay match
$t_{PE-ON}$	PE on-time	-	-	5.0	$\mu s$	$V_{PE} = 1.7 \sim 5.25V$ $V_{DD} = 7.5 \sim 11.5V$ $-20 \sim 85^\circ C$
$t_{PE-OFF}$	PE off-time	-	-	4.0	$\mu s$	

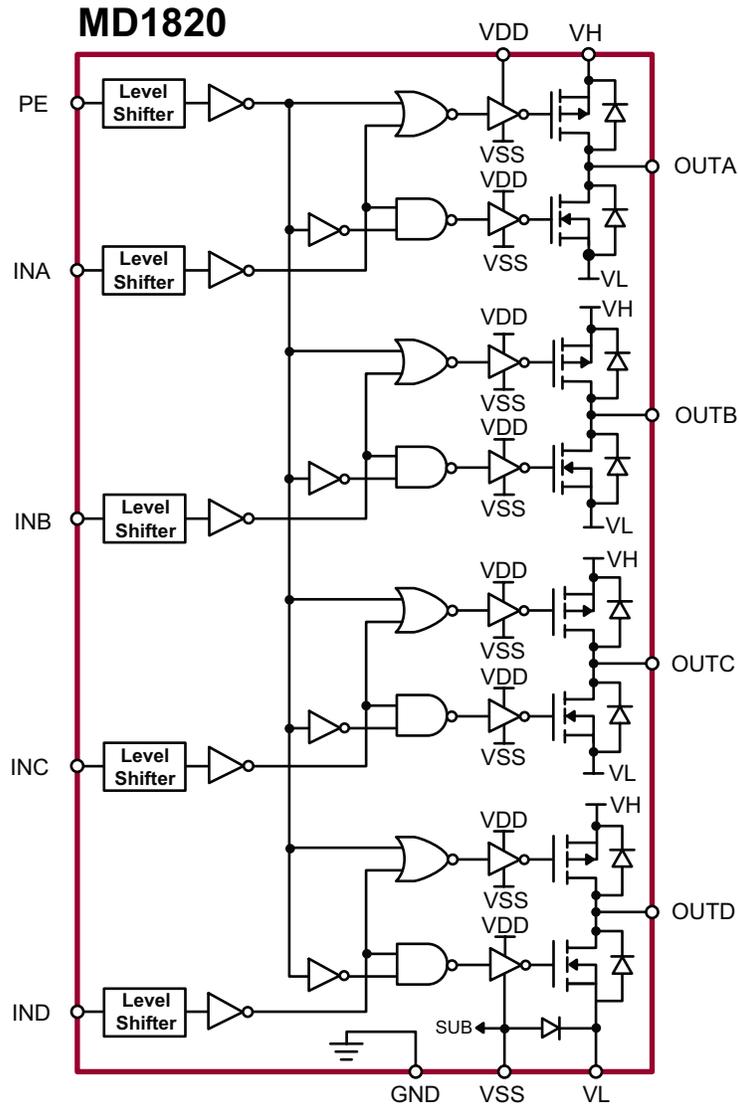
**Logic Truth Table**

Logic Inputs		Output
PE	IN	
H	L	$V_L$
H	H	$V_H$
L	X	High Z

Simplified Block Diagram

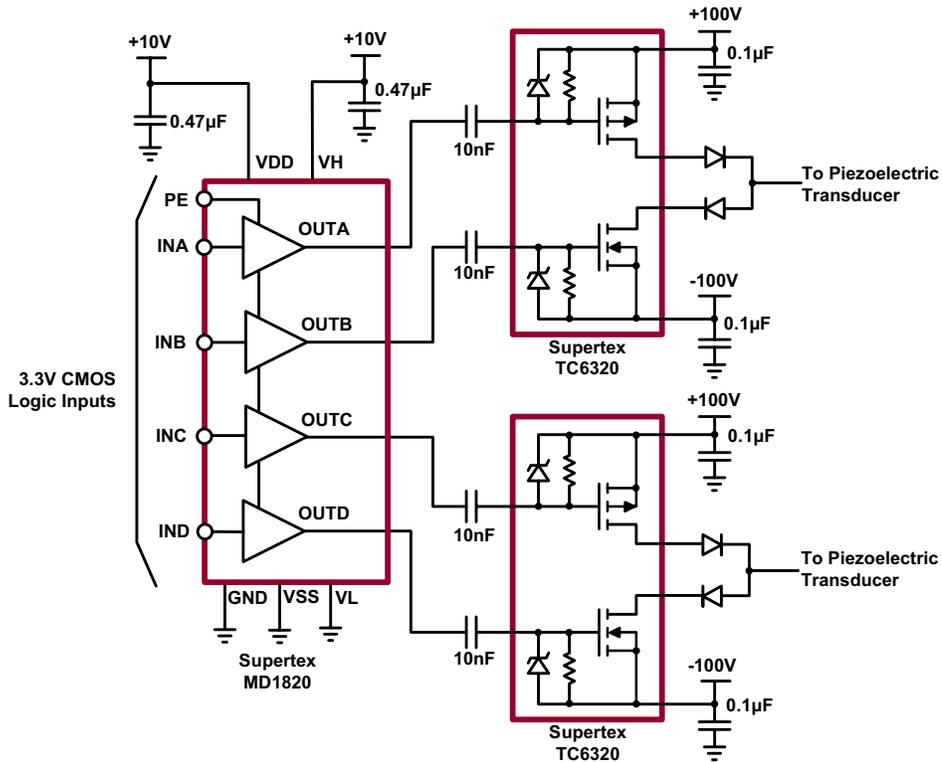


Detailed Block Diagram

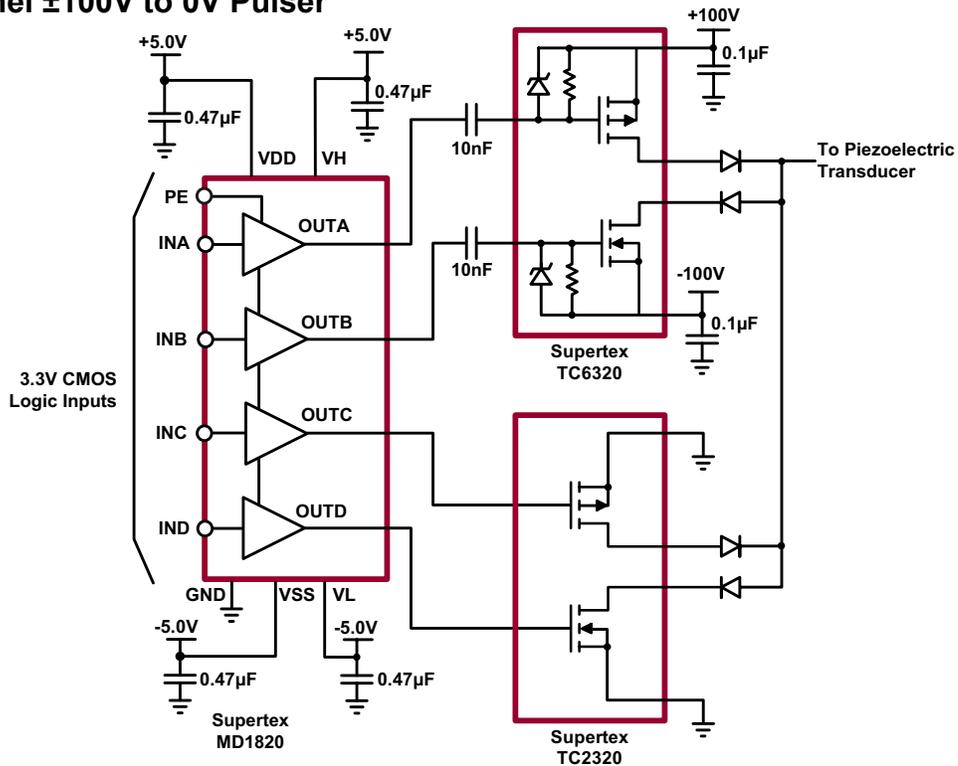


## Typical Applications

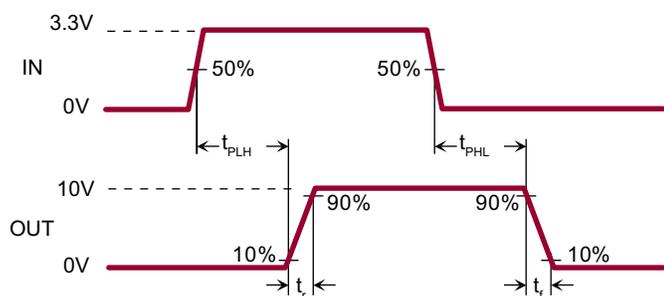
### 2-Channel +100V to -100V Pulser



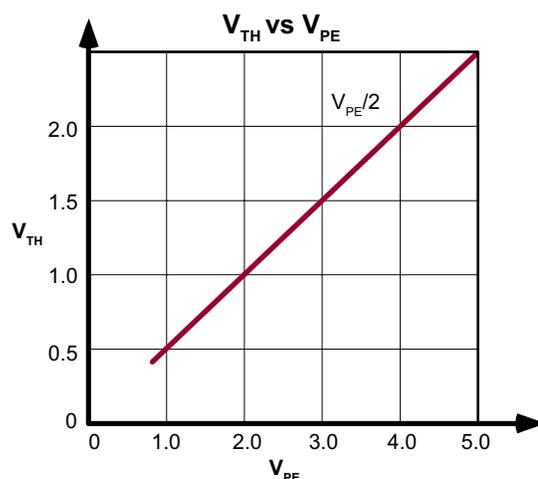
### Single Channel ±100V to 0V Pulser



## Timing Diagram



## $V_{TH} / V_{PE}$ Curve



## Application Information

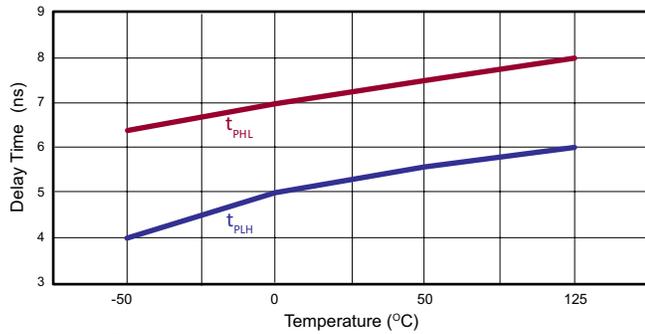
For proper operation of the MD1820, low inductance bypass capacitors should be used on the various supply pins. The GND pin should be connected to the logic ground. The INA, INB, INC, IND, and PE pins should be connected to a logic source with a swing of GND to PE, where PE is 1.8 to 5.0V. Good trace practices should be followed corresponding to the desired operating speed. The internal circuitry of the MD1820 is capable of operating up to 100MHz, with the primary speed limitation being the loading effects of the load capacitance. Because of this speed and the high transient currents that result with capacitive loads, the bypass capacitors should be as close to the chip pins as possible. Unless the load specifically requires bipolar drive, the VSS and VL pins should have low inductance feed-through connections directly to a ground plane. If these voltages are not zero, then they need bypass capacitors in a manner similar to the positive power supplies. The power connection VDD should have a ceramic bypass capacitor to the ground plane with short leads and decoupling components to prevent resonance in the powerleads.

The voltages of VH and VL decide the output signal levels. These two pins can draw fast transient currents of up to 2.0A, so they should be provided with an appropriate bypass

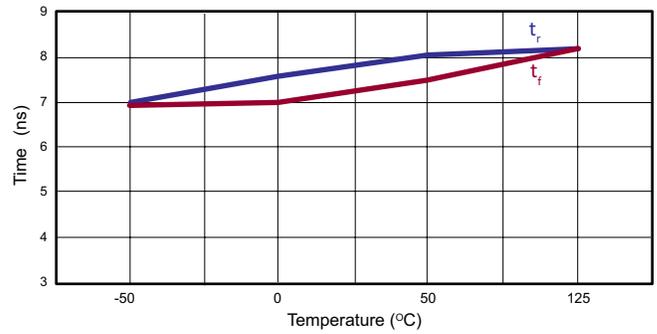
capacitor located next to the chip pins. A ceramic capacitor of up to 1.0 $\mu$ F may be appropriate, with a series ferrite bead to prevent resonance in the power supply lead coming to the capacitor. Pay particular attention to minimizing trace lengths, current loop area and using sufficient trace width to reduce inductance. Surface mount components are highly recommended. Since the output impedance of this driver is very low, in some cases it may be desirable to add a small series resistance in series with the output signal to obtain better waveform transitions at the load terminals. This will of course reduce the output voltage slew rate at the terminals of a capacitive load.

Pay particular attention that parasitic couplings are minimized from the output to the input signal terminals. The parasitic feedback may cause oscillations or spurious waveform shapes on the edges of signal transitions. Since the input operates with signals down to 1.8V even small coupled voltages may cause problems. Use of a solid ground plane and good power and signal layout practices will prevent this problem. Be careful that a circulating ground return current from a capacitive load cannot react with common inductance to cause noise voltages in the input logic circuitry.

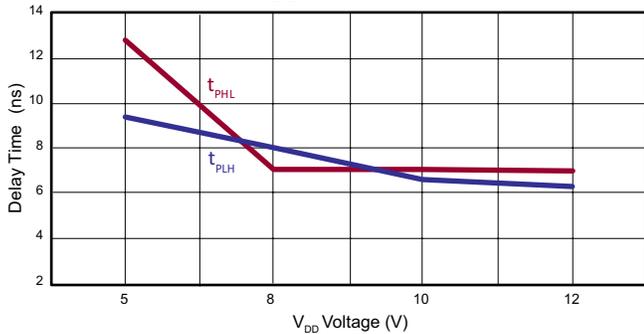
MD1820 Delay vs Temperature



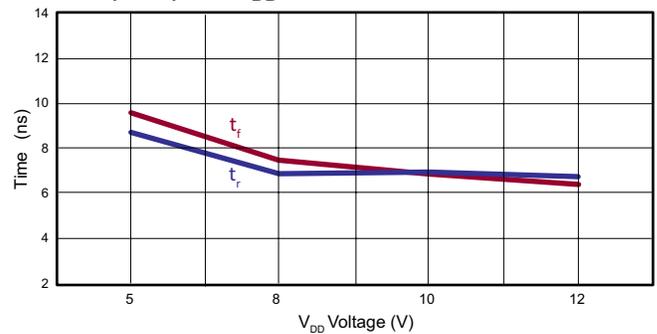
MD1820 t<sub>r</sub> & t<sub>f</sub> vs Temperature



MD1820 Delay vs V<sub>DD</sub>



MD1820 t<sub>r</sub> & t<sub>f</sub> vs V<sub>DD</sub>

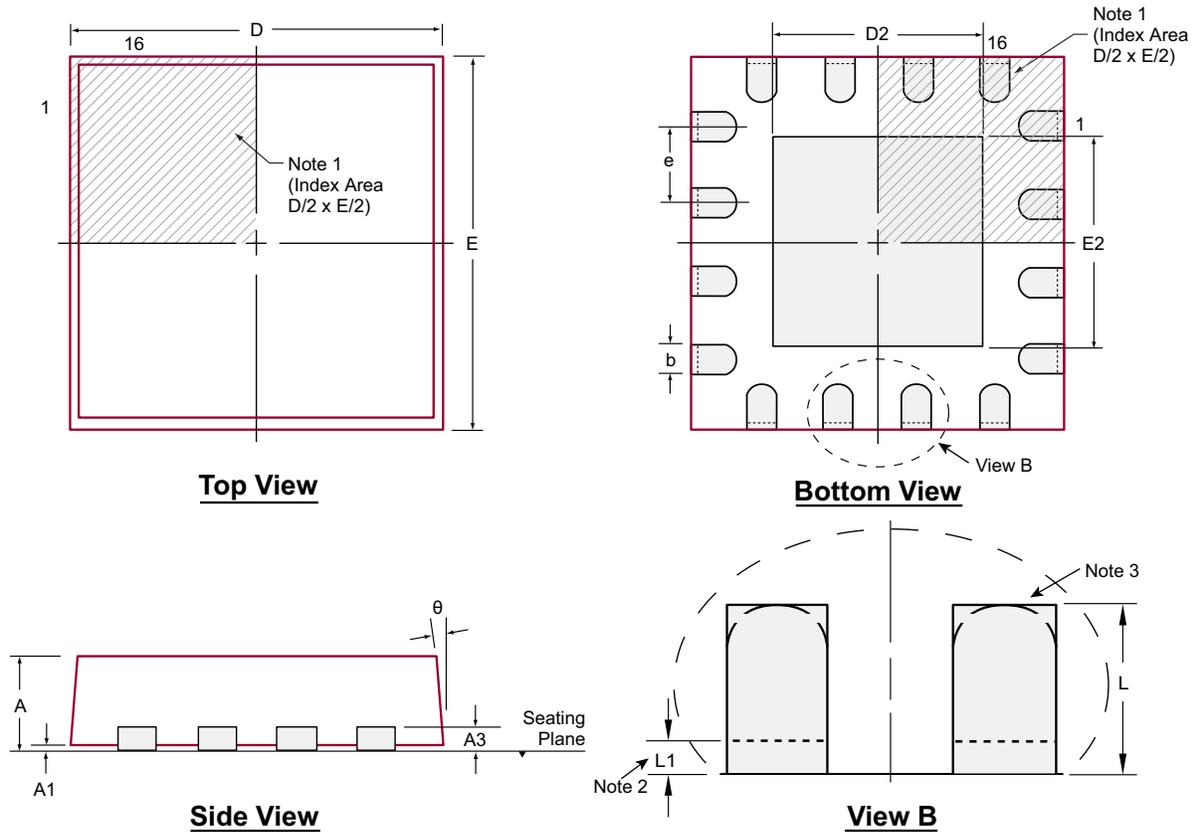


## Pin Description

Pin #	Function	Description
1	INB	Logic input.
2	VDD	High side supply voltage.
3	VSS	Low side supply voltage. VSS is also connected to the IC substrate. It is required to connect to the most negative potential of voltage supplies.
4	INC	Logic input.
5	IND	
6	GND	Logic input ground reference.
7	VL	Supply voltage for N-channel output stage.
8	OUTC	Output drivers
9	OUTD	
10, 11	VH	Supply voltage for P-channel output stage.
12	OUTA	Output drivers
13	OUTB	
14	VL	Supply voltage for N-channel output stage.
15	PE	Power enable logic input. When PE is high, sets the input logic threshold. When PE is low, all outputs are at default state (see truth table) and IC in standby mode.
16	INA	Logic input.
Substrate		The IC substrate is internally connected to the thermal pad. Thermal pad and VSS must be connected externally.

# 16-Lead QFN Package Outline (K6)

3.00x3.00mm body, 1.00mm height (max), 0.50mm pitch



**Notes:**

1. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.
2. Depending on the method of manufacturing, a maximum of 0.15mm pullback (L1) may be present.
3. The inner tip of the lead may be either rounded or square.

Symbol		A	A1	A3	b	D	D2	E	E2	e	L	L1	θ
Dimension (mm)	MIN	0.80	0.00	0.20 REF	0.18	2.85*	1.50	2.85*	1.50	0.50 BSC	0.20†	0.00	0°
	NOM	0.90	0.02		0.25	3.00	1.65	3.00	1.65		0.30†	-	-
	MAX	1.00	0.05		0.30	3.15*	1.80	3.15*	1.80		0.45	0.15	14°

JEDEC Registration MO-220, Variation VEED-4, Issue K, June 2006.

\* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

**Drawings not to scale.**

**Supertex Doc.#:** DSPD-16QFNK63X3P050, Version A092909.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

**Supertex inc.** does not recommend the use of its products in life support applications, and will not knowingly sell them for use in such applications unless it receives an adequate "product liability indemnification insurance agreement." **Supertex inc.** does not assume responsibility for use of devices described, and limits its liability to the replacement of the devices determined defective due to workmanship. No responsibility is assumed for possible omissions and inaccuracies. Circuitry and specifications are subject to change without notice. For the latest product specifications refer to the **Supertex inc.** (website: <http://www.supertex.com>)

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкуренеспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)